

NCV4274, NCV4274A

400 mA 2% and 4% Voltage Regulator Family

Description

The NCV4274 and NCV4274A is a precision micro-power voltage regulator with an output current capability of 400 mA available in the DPAK, D2PAK and SOT-223 packages.

The output voltage is accurate within $\pm 2.0\%$ or $\pm 4.0\%$ depending on the version with a maximum dropout voltage of 0.5 V with an input up to 40 V. Low quiescent current is a feature drawing only 150 μA with a 1 mA load. This part is ideal for automotive and all battery operated microprocessor equipment.

The regulator is protected against reverse battery, short circuit, and thermal overload conditions. The device can withstand load dump transients making it suitable for use in automotive environments.

Features

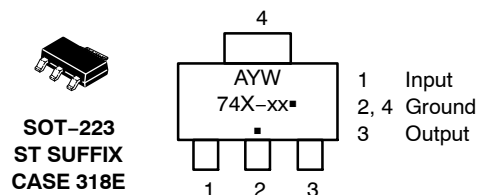
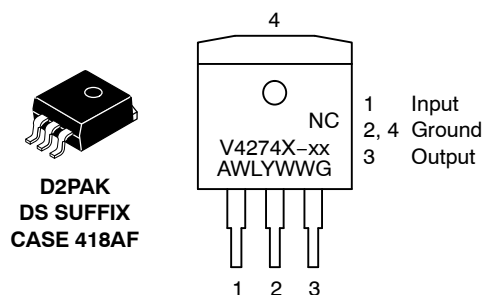
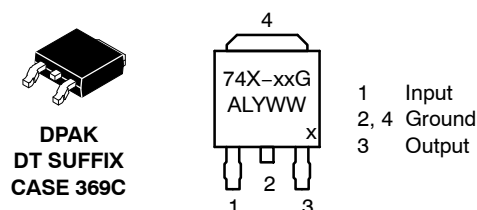
- 2.5, 3.3 V, 5.0 V, 8.5 V, $\pm 2.0\%$ Output Options
- 2.5, 3.3 V, 5.0 V, $\pm 4.0\%$ Output Options
- Low 150 μA Quiescent Current at 1 mA load current
- 400 mA Output Current Capability
- Fault Protection
 - -42 V Reverse Voltage
 - Short Circuit
 - Thermal Overload
- Very Low Dropout Voltage
- AEC-Q100 Qualified and PPAP Capable
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These are Pb-Free Devices



ON Semiconductor®

<http://onsemi.com>

MARKING DIAGRAMS



X = A or blank
xx = Voltage Ratings
A = Assembly Location
L, WL = Wafer Lot
Y = Year
WW, W = Work Week
G, ▪ = Pb-Free Package

(*Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 15 of this data sheet.

NCV4274, NCV4274A

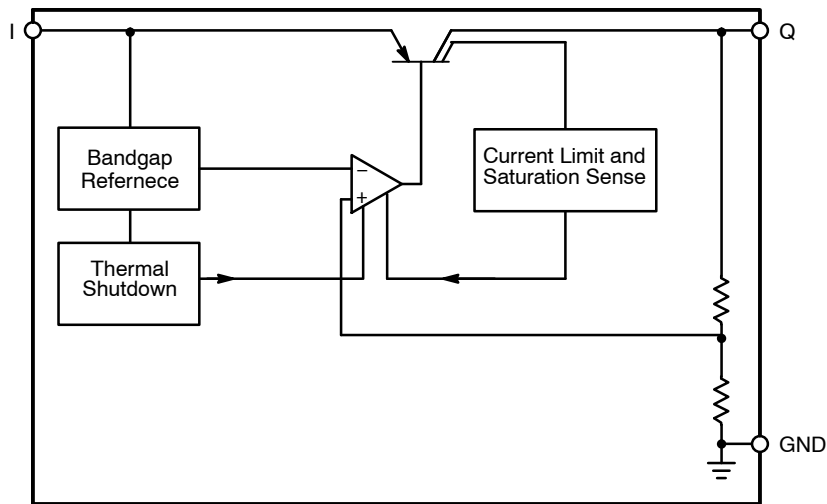


Figure 1. Block Diagram

Pin Definitions and Functions

Pin No.	Symbol	Function
1	I	Input; Bypass directly at the IC a ceramic capacitor to GND.
2,4	GND	Ground
3	Q	Output; Bypass with a capacitor to GND.

1. DPAK 3LD package code 6025
2. D2PAK 3LD package code 6083

ABSOLUTE MAXIMUM RATINGS

Pin Symbol, Parameter		Symbol	Condition	Min	Max	Unit
I, Input-to-Regulator	Voltage	V_I		-42	45	V
	Current	I_I		Internally Limited	Internally Limited	
I, Input peak Transient Voltage to Regulator with Respect to GND		V_I			60	V
Q, Regulated Output	Voltage	V_Q	$V_Q = V_I$	-1.0	40	V
	Current	I_Q		Internally Limited	Internally Limited	
GND, Ground Current		I_{GND}		-	100	mA
Junction Temperature		T_J		-	150	°C
Storage Temperature		T_{Stg}		-50	150	°C
ESD Capability, Human Body Model		ESD _{HB}		4		kV
ESD Capability, Machine Model		ESD _{MM}		200		V
ESD Capability, Charged Device Model		ESD _{CDM}		1		kV

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

3. This device series incorporates ESD protection and is tested by the following methods:
 ESD HBM tested per AEC-Q100-002 (EIA/JESD22-A114)
 ESD MM tested per AEC-Q100-003 (EIA/JESD22-A115)
 ESD CDM tested per EIA/JES D22/C101, Field Induced Charge Model

NCV4274, NCV4274A

OPERATING RANGE

Parameter	Symbol	Condition	Min	Max	Unit
Input Voltage (8.5 V Version)	V_I		9.0	40	V
Input Voltage (5.0 V Version)	V_I		5.5	40	V
Input Voltage (3.3 V, and 2.5 V Version)	V_I		4.5	40	V
Junction Temperature	T_J		-40	150	°C

THERMAL RESISTANCE

Parameter		Symbol	Condition	Min	Max	Unit
Junction-to-Ambient	DPAK	R_{thja}		–	70 (Note 4)	°C/W
Junction-to-Ambient	D2PAK	R_{thja}		–	60 (Note 4)	°C/W
Junction-to-Case	DPAK	R_{thjc}		–	4	°C/W
Junction-to-Case	D2PAK	R_{thjc}		–	3	°C/W
Junction-to-Tab	SOT-223	Ψ_{JLX} , Ψ_{LX}		–	14.5 (Note 5)	°C/W
Junction-to-Ambient	SOT-223	$R_{\theta JA}$, θ_{JA}		–	169.7 (Note 5)	°C/W

4. Soldered in, minimal footprint, FR4

5. 1 oz copper, 5 mm² copper area, FR4

LEAD FREE SOLDERING TEMPERATURE AND MSL

Parameter		Symbol	Condition	Min	Max	Unit
Lead Free Soldering, (Note 6) Reflow (SMD styles only),	Pb-Free	T_{sld}	60s – 150s Above 217s 40s Max at Peak	–	265 pk	°C
Moisture Sensitivity Level		MSL	DPAK and D2PAK SOT-223	1 3	– –	

6. Per IPC/JEDEC J-STD-020C

NCV4274, NCV4274A

ELECTRICAL CHARACTERISTICS

-40°C < T_J < 150°C; V_I = 13.5 V unless otherwise noted.

Parameter	Symbol	Test Conditions	Min	Typ	Max	Min	Typ	Max	Unit
			NCV4274A			NCV4274			
REGULATOR									
Output Voltage (8.5 V Version)	V _Q	5 mA < I _Q < 200 mA 9.5 V < V _I < 40 V	8.33	8.5	8.67	–	–	–	V
Output Voltage (8.5 V Version)	V _Q	5 mA < I _Q < 400 mA 9.5 V < V _I < 28 V	8.33	8.5	8.67	–	–	–	V
Output Voltage (5.0 V Version)	V _Q	5 mA < I _Q < 400 mA 6 V < V _I < 28 V	4.9	5.0	5.1	4.8	5.0	5.2	V
Output Voltage (5.0 V Version)	V _Q	5 mA < I _Q < 200 mA 6 V < V _I < 40 V	4.9	5.0	5.1	4.8	5.0	5.2	V
Output Voltage (3.3 V Version)	V _Q	5 mA < I _Q < 400 mA 4.5 V < V _I < 28 V	3.23	3.3	3.37	3.17	3.3	3.43	V
Output Voltage (3.3 V Version)	V _Q	5 mA < I _Q < 200 mA 4.5 V < V _I < 40 V	3.23	3.3	3.37	3.17	3.3	3.43	V
Output Voltage (2.5 V Version)	V _Q	5 mA < I _Q < 400 mA 4.5 V < V _I < 28 V	2.45	2.5	2.55	2.4	2.5	2.6	V
Output Voltage (2.5 V Version)	V _Q	5 mA < I _Q < 200 mA 4.5 V < V _I < 40 V	2.45	2.5	2.55	2.4	2.5	2.6	V
Current Limit	I _Q	–	400	600	–	400	600	–	mA
Quiescent Current	I _q	I _Q = 1 mA V _Q = 8.5 V V _Q = 5.0 V V _Q = 3.3 V V _Q = 2.5 V I _Q = 250 mA V _Q = 8.5 V V _Q = 5.0 V V _Q = 3.3 V V _Q = 2.5 V I _Q = 400 mA V _Q = 8.5 V V _Q = 5.0 V V _Q = 3.3 V V _Q = 2.5 V	– –<						

*Guaranteed by design, not tested in production

NCV4274, NCV4274A

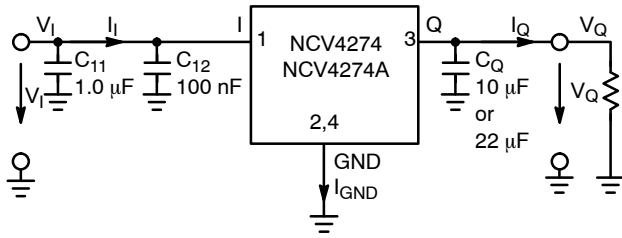


Figure 2. Measuring Circuit

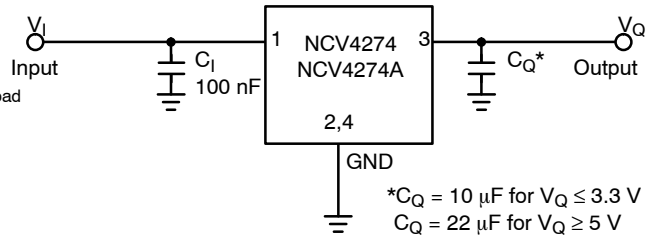


Figure 3. Application Circuit

TYPICAL CHARACTERISTIC CURVES

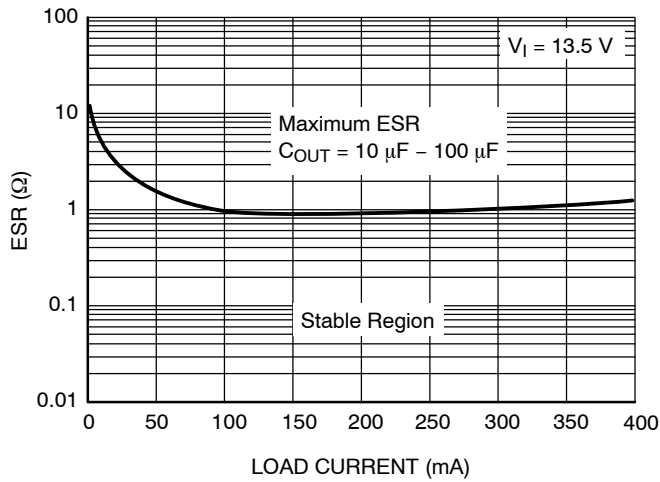


Figure 4. ESR Characterization – 8.5 V Version

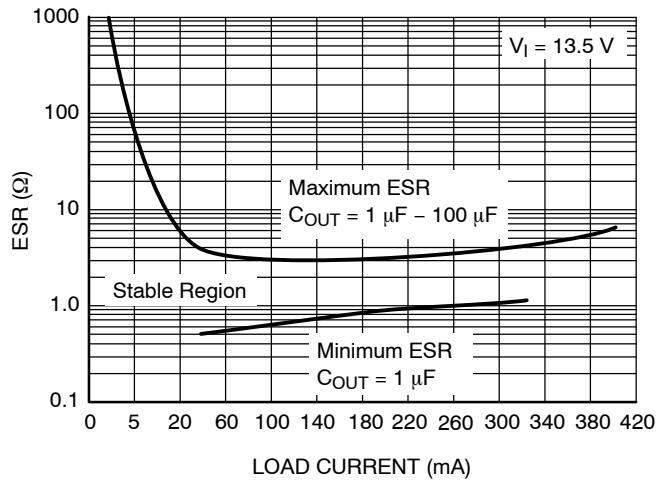


Figure 5. ESR Characterization – 2.5 V, 3.3 V and 5 V Versions

TYPICAL CHARACTERISTIC CURVES – 8.5 V Version

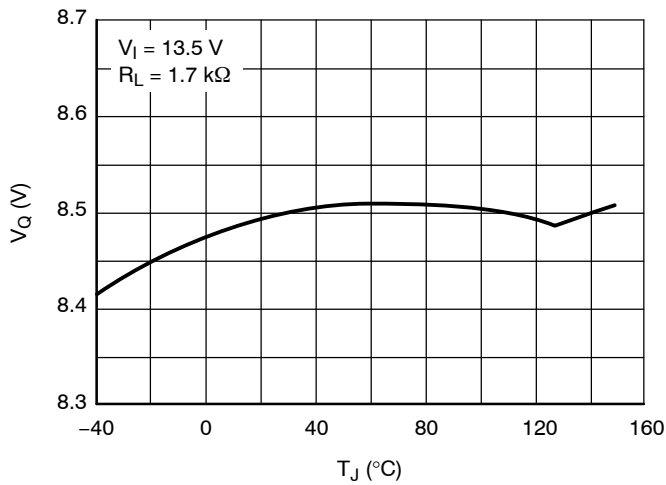


Figure 6. Output Voltage vs. Junction Temperature

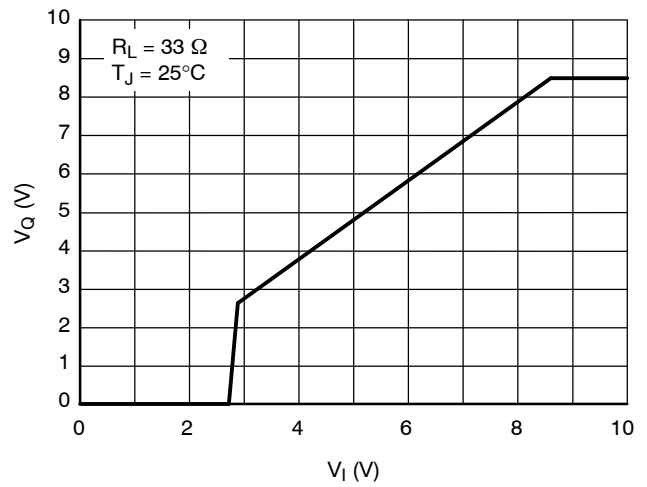


Figure 7. Output Voltage vs. Input Voltage

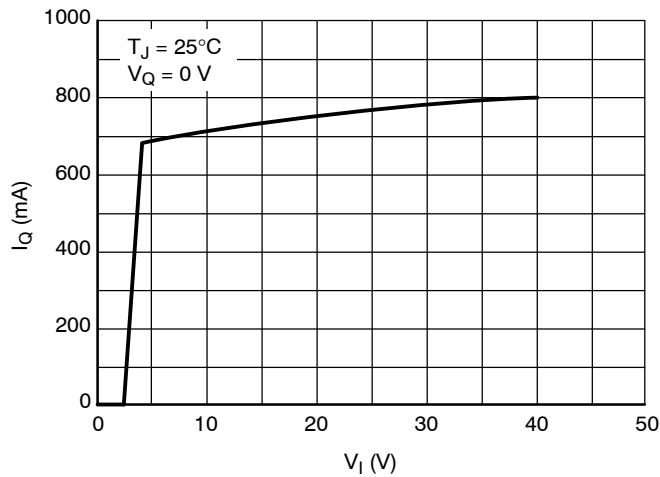


Figure 8. Output Current vs. Input Voltage

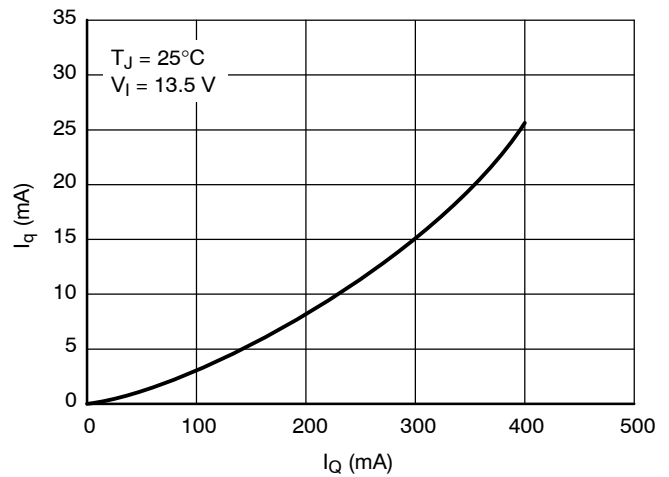


Figure 9. Current Consumption vs. Output Current (High Load)

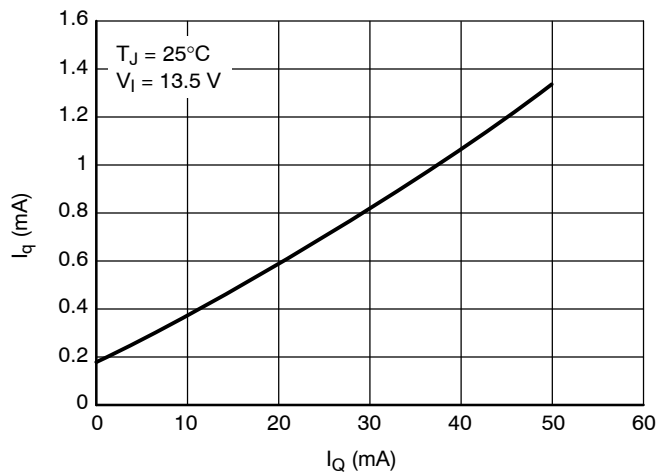


Figure 10. Current Consumption vs. Output Current (Low Load)

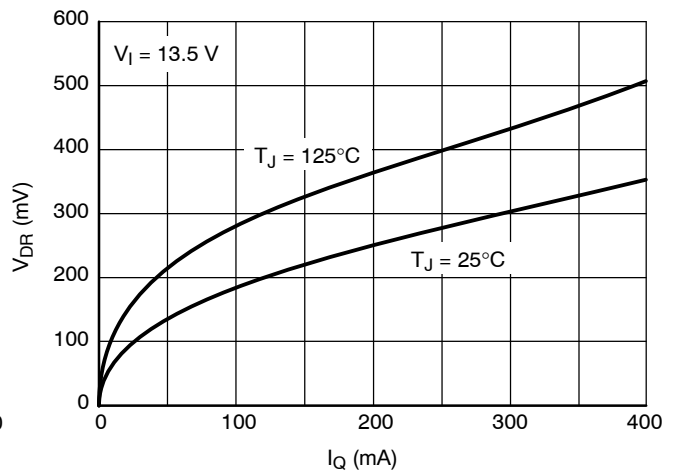


Figure 11. Drop Voltage vs. Output Current

NCV4274, NCV4274A

TYPICAL CHARACTERISTIC CURVES – 8.5 V Version

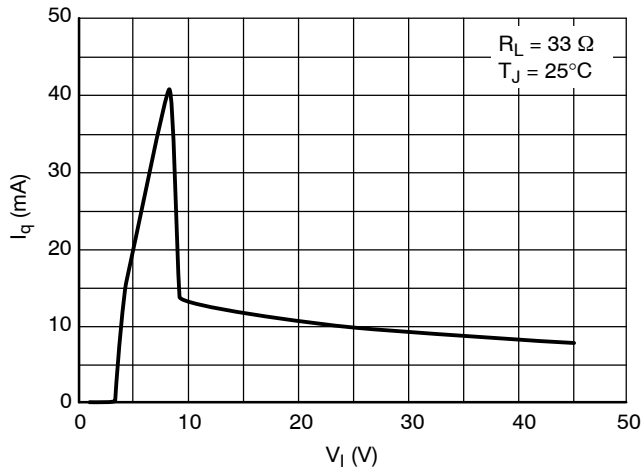


Figure 12. Current Consumption vs. Input Voltage

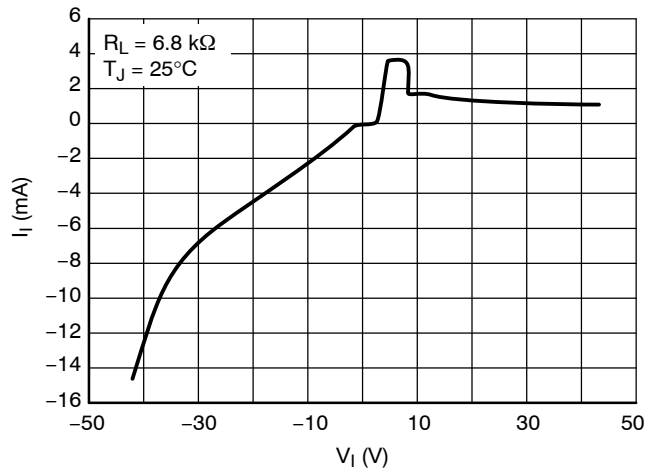


Figure 13. Input Current vs. Input Voltage

TYPICAL CHARACTERISTIC CURVES – 5.0 V Version

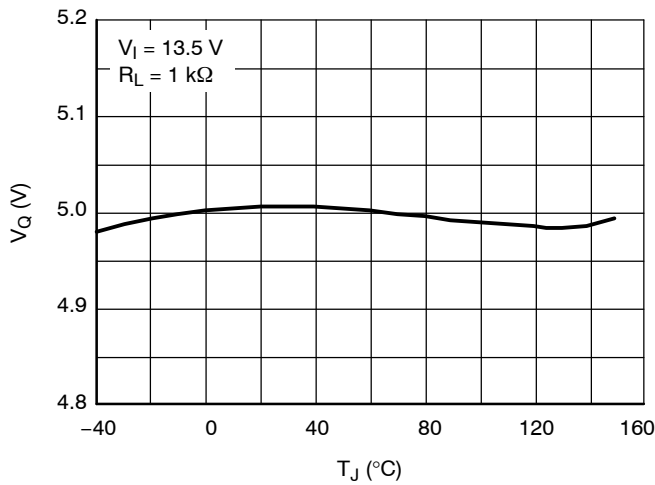


Figure 14. Output Voltage vs. Junction Temperature

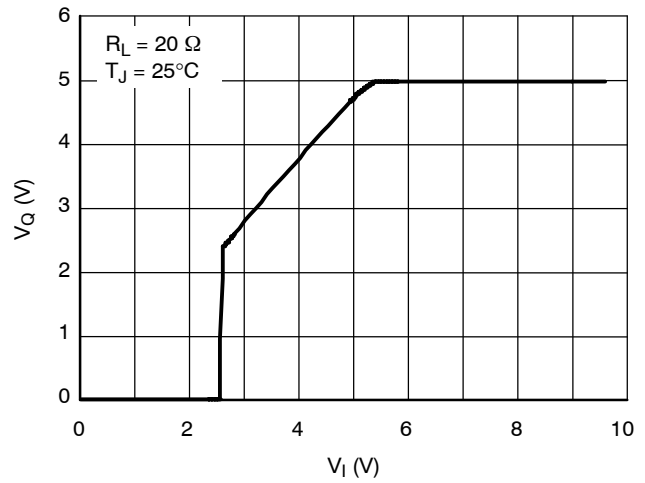


Figure 15. Output Voltage vs. Input Voltage

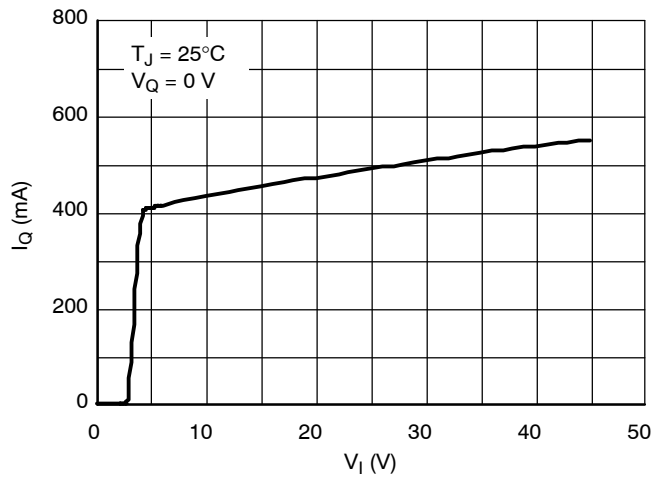


Figure 16. Output Current vs. Input Voltage

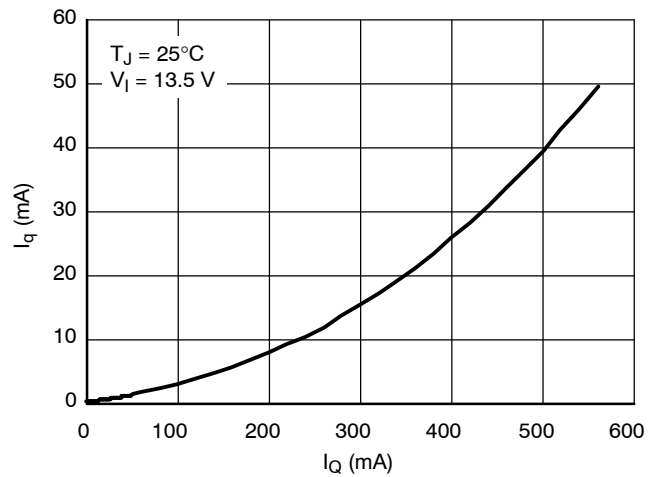


Figure 17. Current Consumption vs. Output Current (High Load)

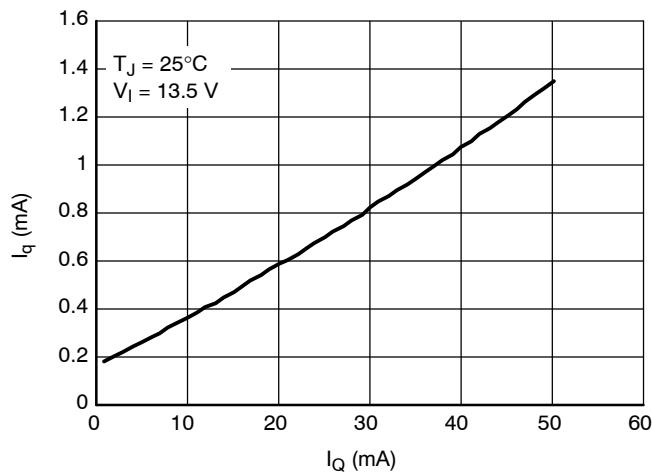


Figure 18. Current Consumption vs. Output Current (Low Load)

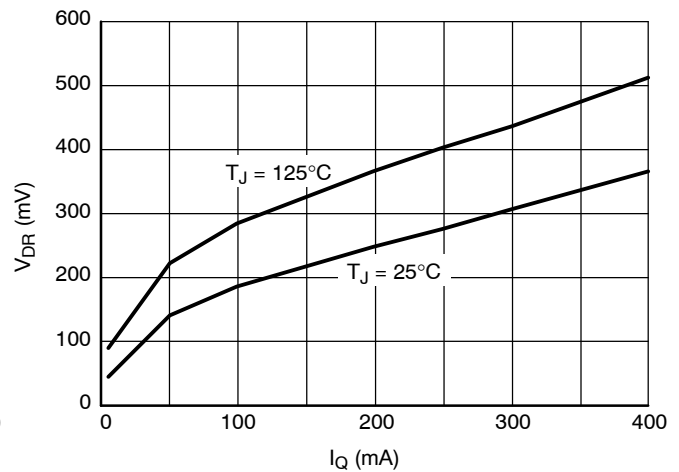


Figure 19. Drop Voltage vs. Output Current

NCV4274, NCV4274A

TYPICAL CHARACTERISTIC CURVES – 5.0 V Version

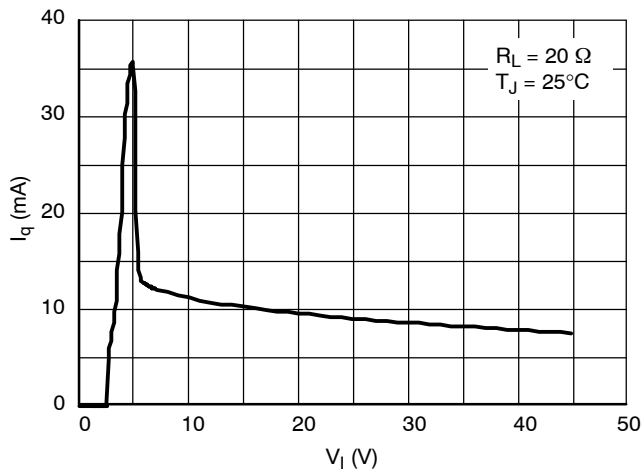


Figure 20. Current Consumption vs. Input Voltage

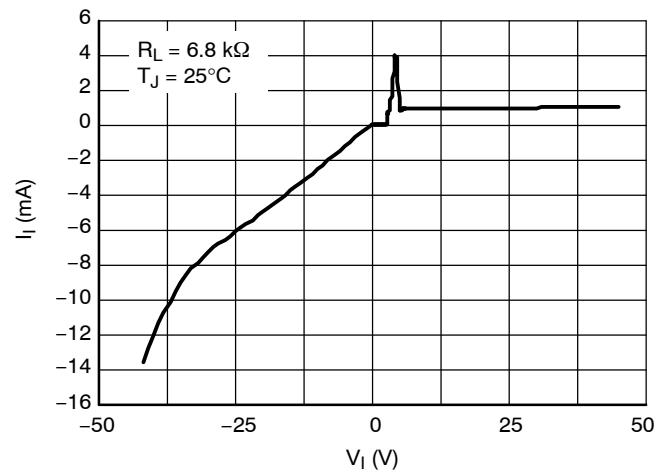


Figure 21. Input Current vs. Input Voltage

TYPICAL CHARACTERISTIC CURVES – 3.3 V Version

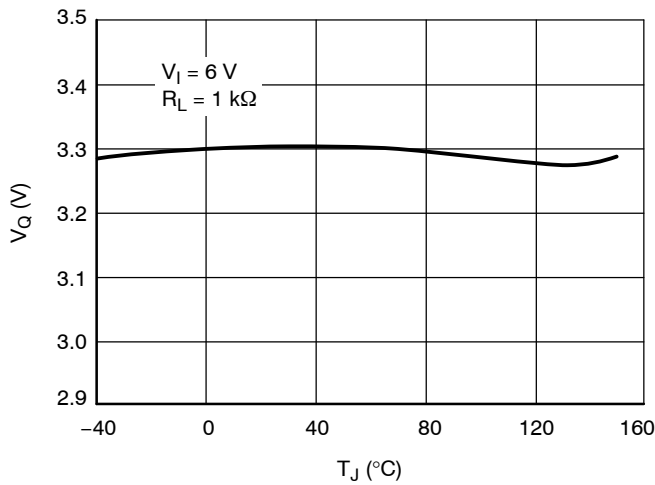


Figure 22. Output Voltage vs. Junction Temperature

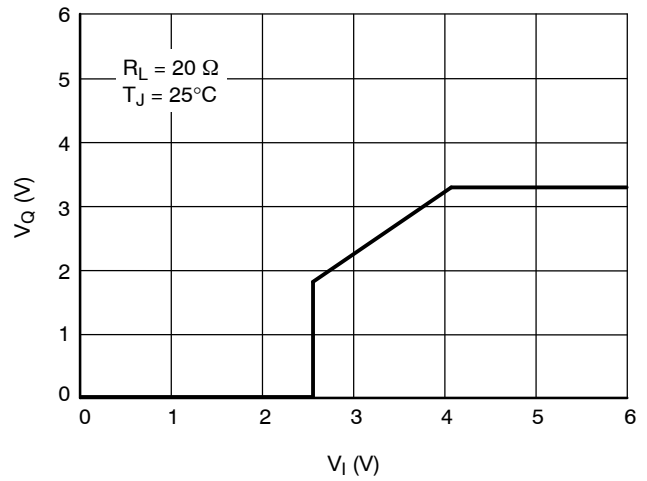


Figure 23. Output Voltage vs. Input Voltage

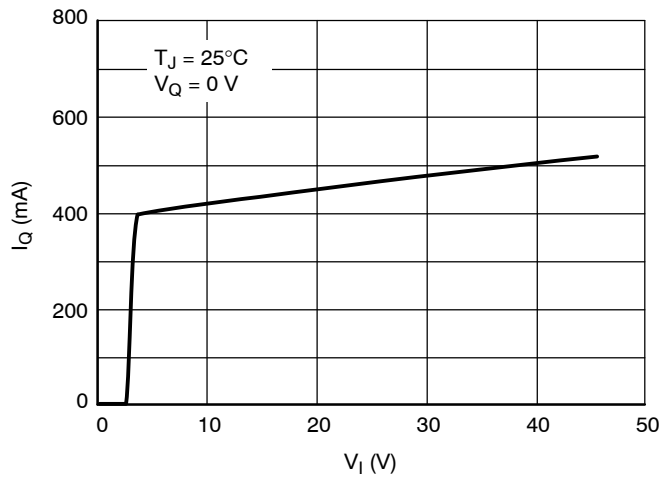


Figure 24. Output Current vs. Input Voltage

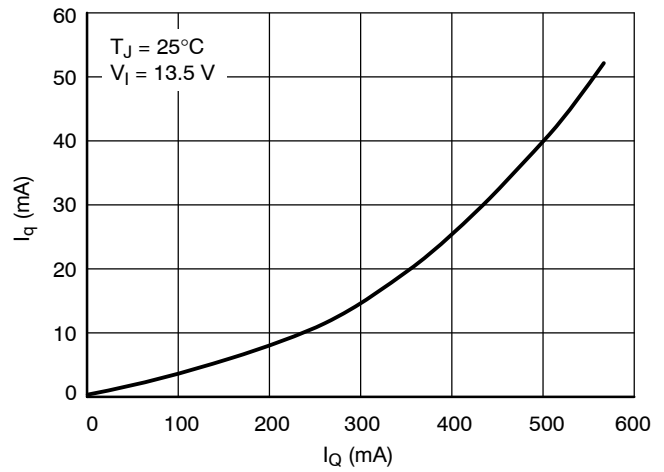


Figure 25. Current Consumption vs. Output Current (High Load)

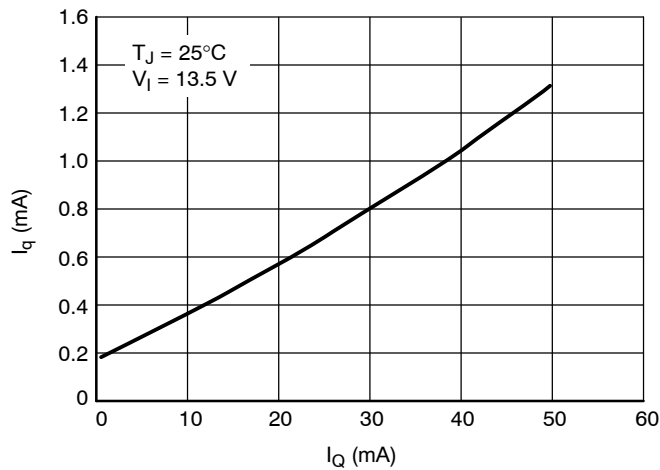


Figure 26. Current Consumption vs. Output Current (Low Load)

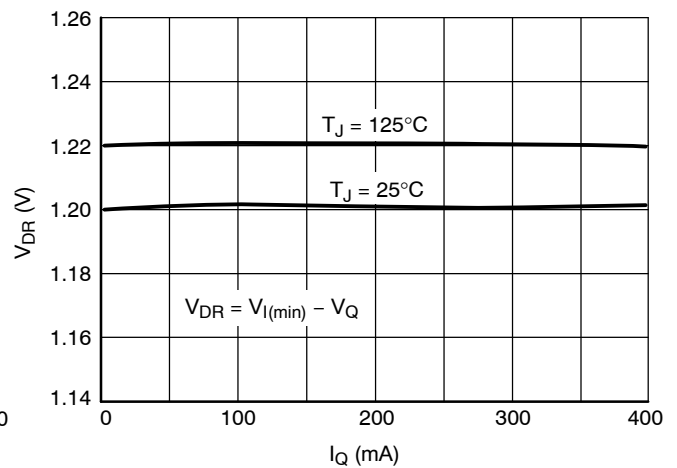


Figure 27. Voltage Drop vs. Output Current

NCV4274, NCV4274A

TYPICAL CHARACTERISTIC CURVES – 3.3 V Version

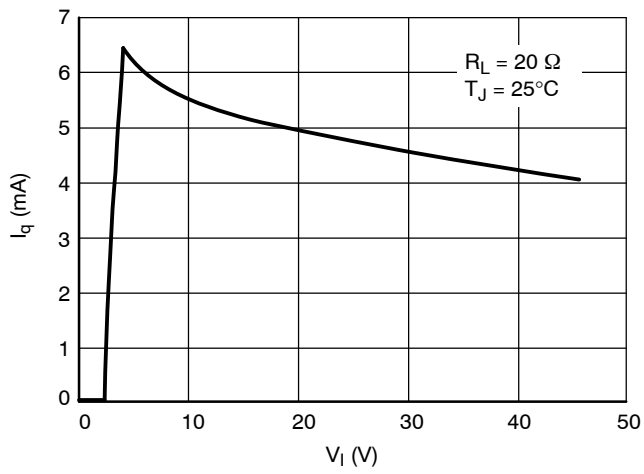


Figure 28. Current Consumption vs. Input Voltage

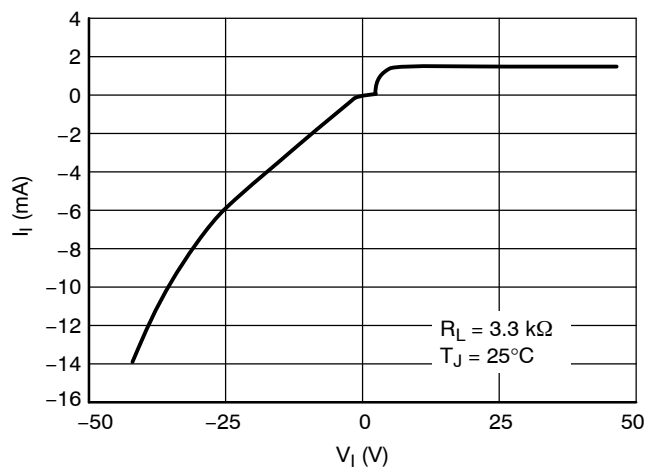


Figure 29. Input Current vs. Input Voltage

TYPICAL CHARACTERISTIC CURVES – 2.5 V Version

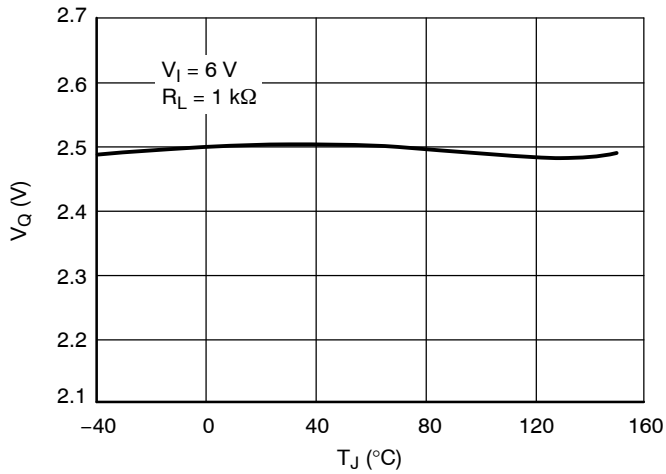


Figure 30. Output Voltage vs. Junction Temperature

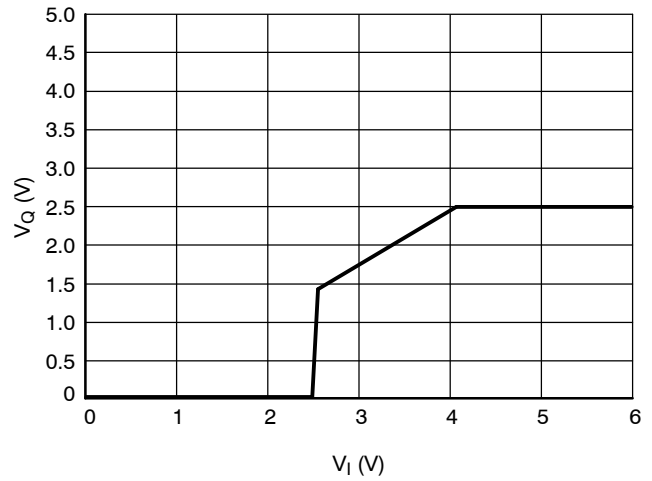


Figure 31. Output Voltage vs. Input Voltage

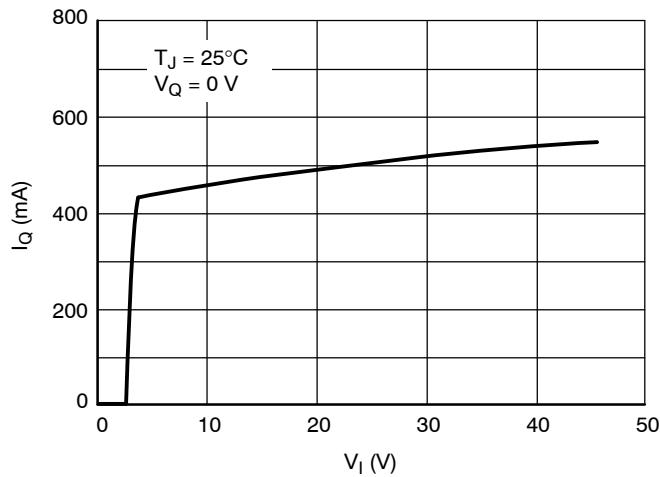


Figure 32. Output Current vs. Input Voltage

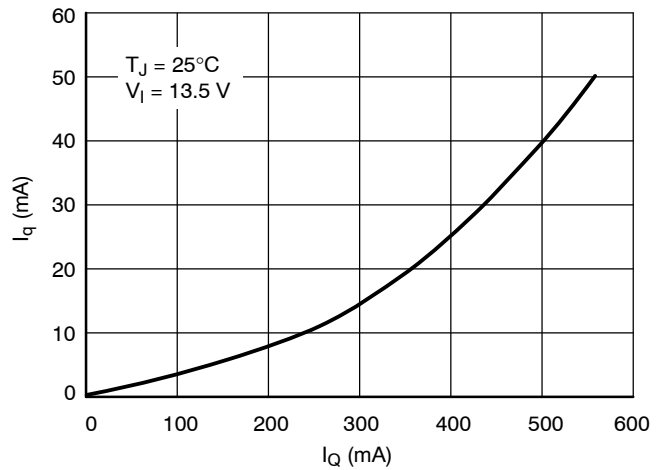


Figure 33. Current Consumption vs. Output Current (High Load)

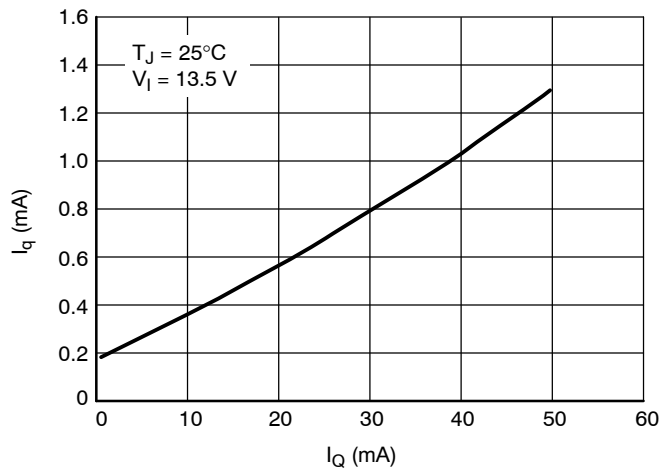


Figure 34. Current Consumption vs. Output Current (Low Load)

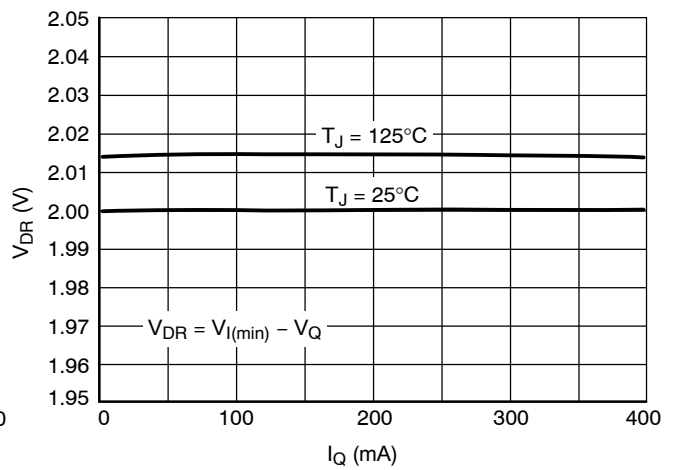


Figure 35. Voltage Drop vs. Output Current

NCV4274, NCV4274A

TYPICAL CHARACTERISTIC CURVES – 2.5 V Version

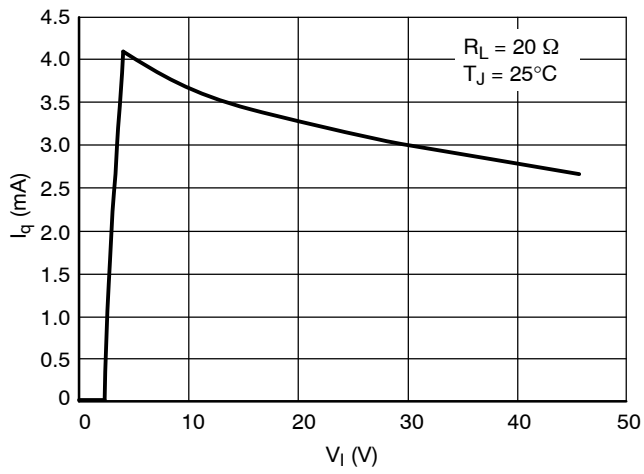


Figure 36. Current Consumption vs. Input Voltage

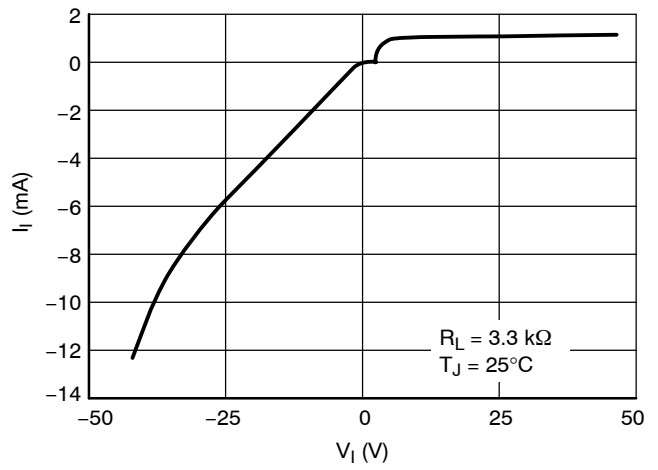


Figure 37. Input Current vs. Input Voltage

APPLICATION DESCRIPTION

Output Regulator

The output is controlled by a precision trimmed reference and error amplifier. The PNP output has saturation control for regulation while the input voltage is low, preventing over saturation. Current limit and voltage monitors complement the regulator design to give safe operating signals to the processor and control circuits.

Stability Considerations

The input capacitor C_{I1} in Figure 2 is necessary for compensating input line reactance. Possible oscillations caused by input inductance and input capacitance can be damped by using a resistor of approximately $1\ \Omega$ in series with C_{I2} .

The output or compensation capacitor helps determine three main characteristics of a linear regulator: startup delay, load transient response and loop stability.

The capacitor value and type should be based on cost, availability, size and temperature constraints. The aluminum electrolytic capacitor is the least expensive solution, but, if the circuit operates at low temperatures (-25°C to -40°C), both the value and ESR of the capacitor will vary considerably. The capacitor manufacturer's data sheet usually provides this information.

The value for the output capacitor C_O shown in Figure 2 should work for most applications; however, it is not necessarily the optimized solution. Stability is guaranteed at values $C_O \geq 2.2\ \mu\text{F}$ and an $\text{ESR} \leq 2.5\ \Omega$ within the operating temperature range. Actual limits are shown in a graph in the Typical Performance Characteristics section.

Calculating Power Dissipation in a Single Output Linear Regulator

The maximum power dissipation for a single output regulator (Figure 3) is:

$$P_{D(\max)} = [V_{I(\max)} - V_{Q(\min)}]I_{Q(\max)} + V_{I(\max)}I_q \quad (\text{eq. 1})$$

Where:

$V_{I(\max)}$ is the maximum input voltage,

$V_{Q(\min)}$ is the minimum output voltage,

$I_{Q(\max)}$ is the maximum output current for the application, and

I_q is the quiescent current the regulator consumes at $I_{Q(\max)}$.

Once the value of $P_{D(\max)}$ is known, the maximum permissible value of $R_{\theta JA}$ can be calculated:

$$P_{\theta JA} = \frac{(150^{\circ}\text{C} - T_A)}{P_D} \quad (\text{eq. 2})$$

The value of $R_{\theta JA}$ can then be compared with those in the package section of the data sheet. Those packages with $R_{\theta JA}$'s less than the calculated value in Equation 2 will keep the die temperature below 150°C . In some cases, none of the packages will be sufficient to dissipate the heat generated by the IC, and an external heat sink will be required. The current flow and voltages are shown in the Measurement Circuit Diagram.

Heat Sinks

A heat sink effectively increases the surface area of the package to improve the flow of heat away from the IC and into the surrounding air.

Each material in the heat flow path between the IC and the outside environment will have a thermal resistance. Like series electrical resistances, these resistances are summed to determine the value of $R_{\theta JA}$:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CS} + R_{\theta SA} \quad (\text{eq. 3})$$

Where:

$R_{\theta JC}$ = the junction-to-case thermal resistance,

$R_{\theta CS}$ = the case-to-heat sink thermal resistance, and

$R_{\theta SA}$ = the heat sink-to-ambient thermal resistance.

$R_{\theta JC}$ appears in the package section of the data sheet.

Like $R_{\theta JA}$, it too is a function of package type. $R_{\theta CS}$ and $R_{\theta SA}$ are functions of the package type, heat sink and the interface between them. These values appear in data sheets of heat sink manufacturers. Thermal, mounting, and heat sinking are discussed in the ON Semiconductor application note AN1040/D, available on the ON Semiconductor Website.

NCV4274, NCV4274A

ORDERING INFORMATION4

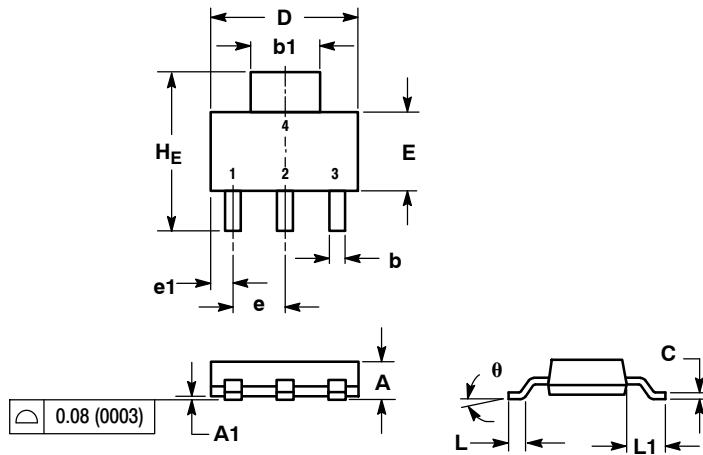
Device	Output Voltage Accuracy	Output Voltage	Package	Shipping†
NCV4274ADS85R4G	2%	8.5 V	D2PAK (Pb-Free)	800 / Tape & Reel
NCV4274DS50G	4%	5.0 V	D2PAK (Pb-Free)	50 Units / Rail
NCV4274DS50R4G	4%	5.0 V	D2PAK (Pb-Free)	800 / Tape & Reel
NCV4274DT50RKG	4%	5.0 V	DPAK (Pb-Free)	2500 / Tape & Reel
NCV4274ADS50G	2%	5.0 V	D2PAK (Pb-Free)	50 Units / Rail
NCV4274ADS50R4G	2%	5.0 V	D2PAK (Pb-Free)	800 / Tape & Reel
NCV4274ADT50RKG	2%	5.0 V	DPAK (Pb-Free)	2500 / Tape & Reel
NCV4274ST33T3G	4%	3.3 V	SOT-223 (Pb-Free)	4000 / Tape & Reel
NCV4274DT33RKG	4%	3.3 V	DPAK (Pb-Free)	2500 / Tape & Reel
NCV4274AST33T3G	2%	3.3 V	SOT-223 (Pb-Free)	4000 / Tape & Reel
NCV4274ADT33RKG	2%	3.3 V	DPAK (Pb-Free)	2500 / Tape & Reel
NCV4274ADS33R4G	2%	3.3 V	D2PAK (Pb-Free)	800 / Tape & Reel
NCV4274ST25T3G	4%	2.5 V	SOT-223 (Pb-Free)	4000 / Tape & Reel
NCV4274AST25T3G	2%	2.5 V	SOT-223 (Pb-Free)	4000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NCV4274, NCV4274A

PACKAGE DIMENSIONS

SOT-223 (TO-261)
CASE 318E-04
ISSUE N

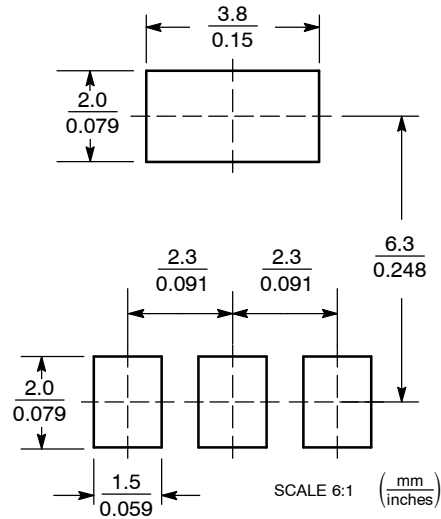


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCH.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
c	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
e	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L	0.20	---	---	0.008	---	---
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	---	10°	0°	---	10°

SOLDERING FOOTPRINT*

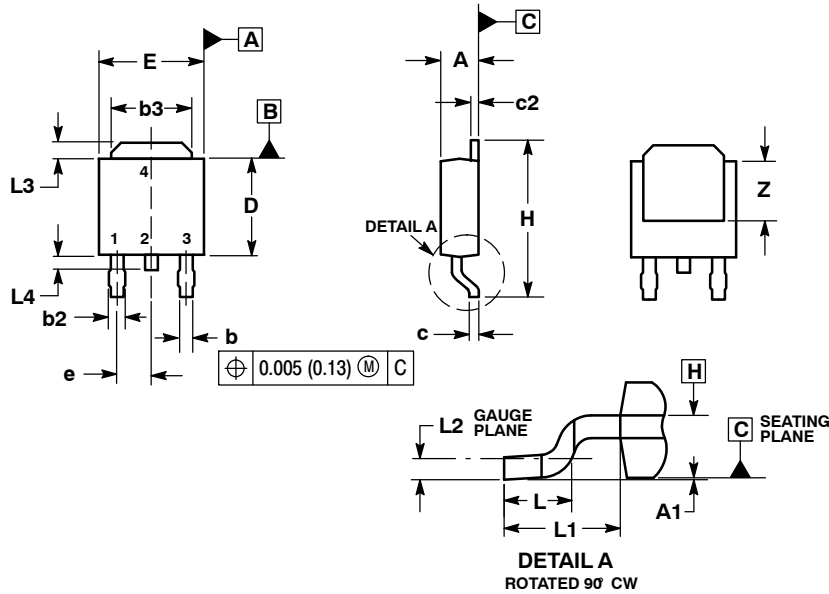


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NCV4274, NCV4274A

PACKAGE DIMENSIONS

DPAK (SINGLE GAUGE) CASE 369C ISSUE D

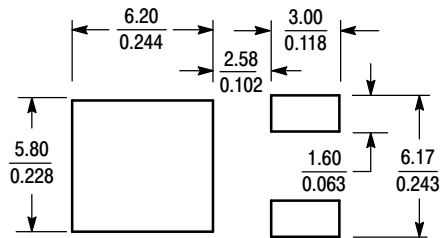


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3 and Z.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.030	0.045	0.76	1.14
b3	0.180	0.215	4.57	5.46
c	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
e	0.090 BSC		2.29 BSC	
H	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.108 REF		2.74 REF	
L2	0.020 BSC		0.51 BSC	
L3	0.035	0.050	0.89	1.27
L4	---	0.040	---	1.01
Z	0.155	---	3.93	---

SOLDERING FOOTPRINT*



SCALE 3:1 $\left(\frac{\text{mm}}{\text{inches}} \right)$

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.